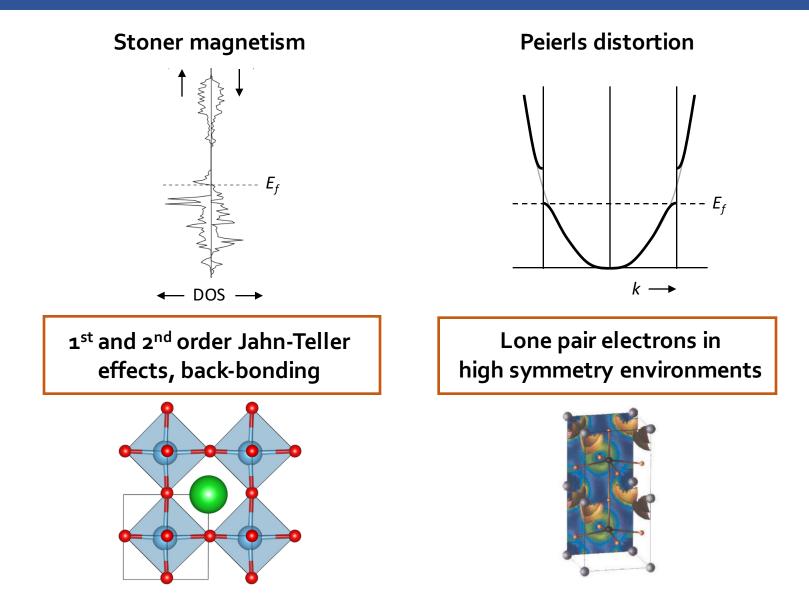
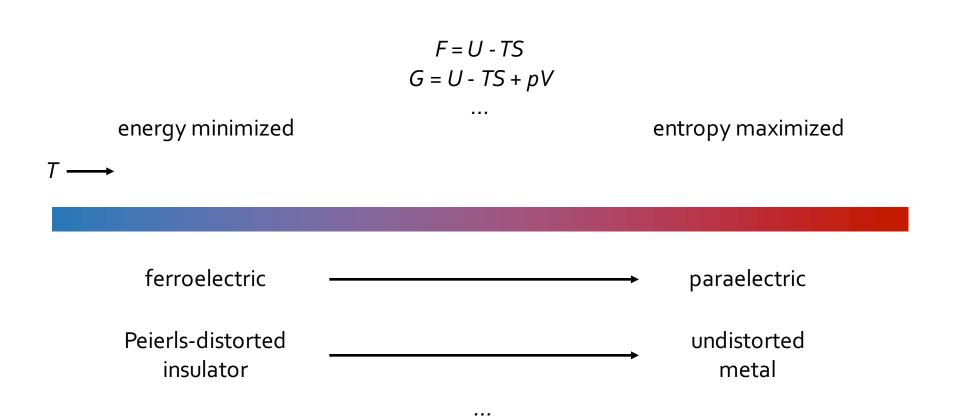
Electronically driven lattice instabilities: Covalent origins and property impacts

Doug Fabini Materials 286G Final Presentation June 1, 2016

Degeneracy begets instability



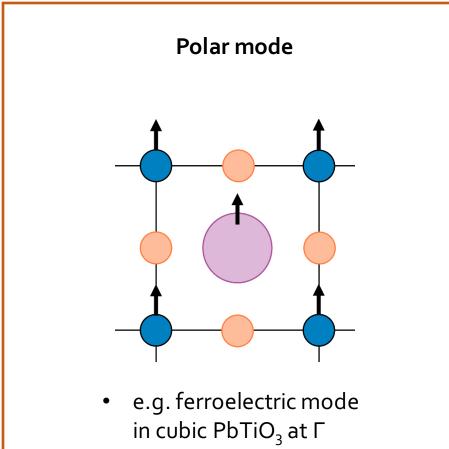
Schildkamp, Fischer. Rhomboedrisches BaTiO₃: Strukturuntersuchung bei 132 K und 196 K, *Z. Kristallogr.*, **1981**, 155, 217 – 226. Seshadri. Visualizing lone pairs in compounds containing heavier congeners of the carbon and nitrogen group elements, *Proc. Indian Acad. Sci. (Chem. Sci.)*, **2001**, 113, 487 – 496.



Thus, systems near instabilities exhibit strongly temperature dependent behavior.

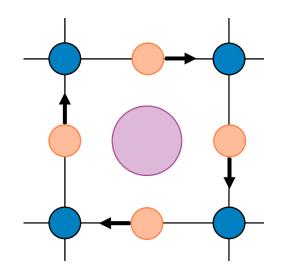
Now consider a high temperature phase, with a mechanically unstable lattice...

Polar versus non-polar lattice instabilities



- Covalently-driven
- Contributes directly to dielectric response

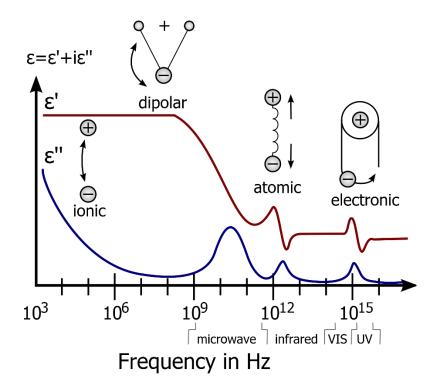
Non-polar mode



- e.g. octahedral rotations in cubic SrTiO₃ at M, R
- Electrostatically-driven

(Simplistic) picture of electrical transport:

Orbital overlap and **electronegativities** (band theory, carrier effective masses) set upper bound on mobility. Scattering of carriers by **defects**, **impurities**, and **phonons** reduces mobility from this limit to its practical value.

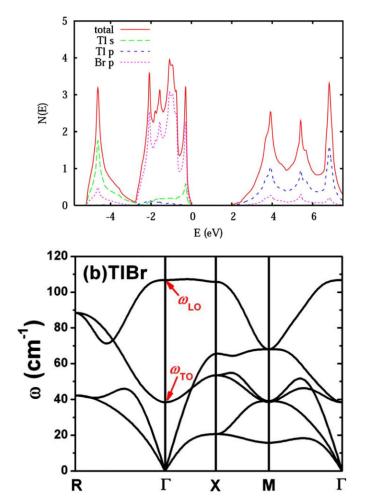


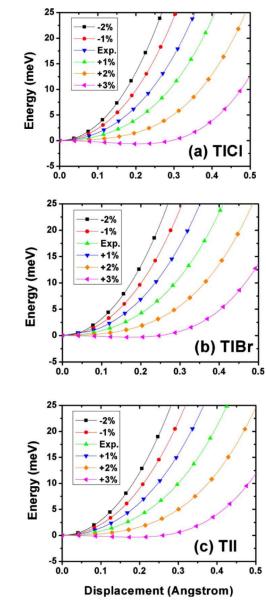
If scattering from charged defects or impurities is dominant, effective dielectric screening can enhance mobilities!

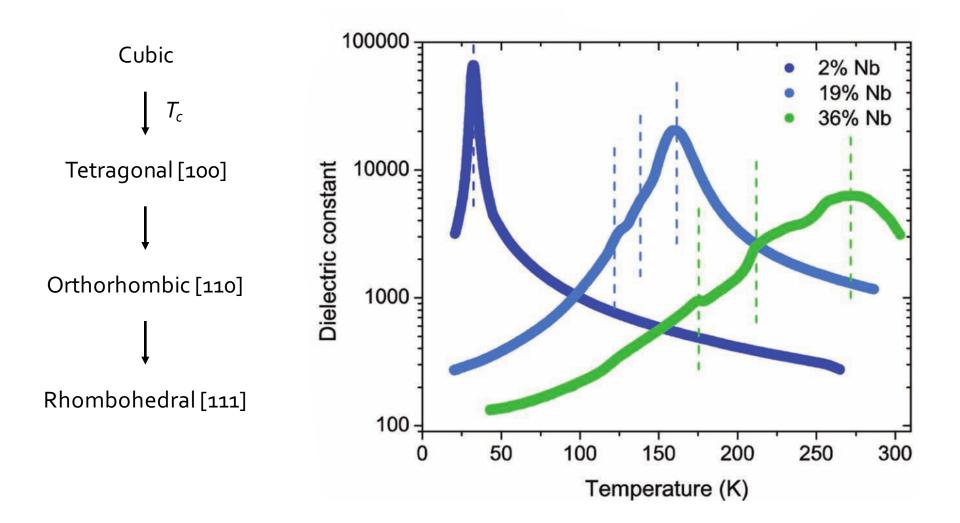
Figure from Beau Lambert, psrc.usm.edu/mauritz/dilect.html

Case study: Lone pair-driven proximal instability in TIX (X = CI, Br, I)

- Lattice expansion, electrostatic penalty to displacement
- Elevated Born charges & LO/TO splitting
- Relation to dielectric properties (Lydanne—Sachs—Teller)



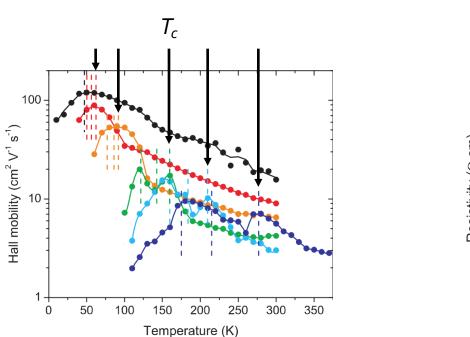


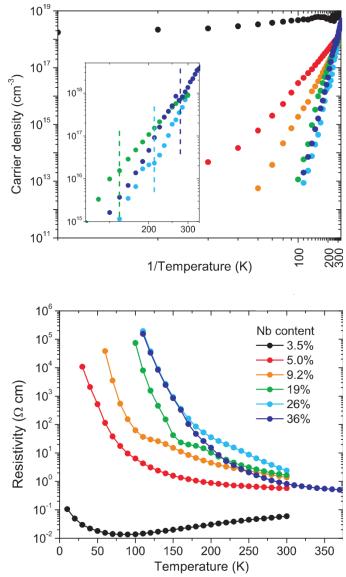


Siemons, McGuire, Cooper, Biegalski, Ivanov, Jellison, Boatner, Sales, Christen. Dielectric-constant-enhanced hall mobility in complex oxides, *Adv. Mater.* **2012**, *24*, 3965 – 3969.

Hall mobility tracks the dielectric response

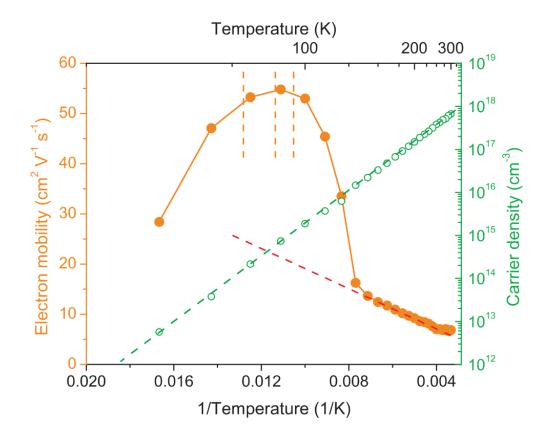
- Ancillary experiments show mobility enhancement not due to other effects
- Additional features from lower T phase transitions in Nb-rich alloys





Siemons, McGuire, Cooper, Biegalski, Ivanov, Jellison, Boatner, Sales, Christen. Dielectric-constant-enhanced hall mobility in complex oxides, *Adv. Mater.* **2012**, *24*, 3965 – 3969.

KTa_{0.919}Nb_{0.092}O₃:Ca



Siemons, McGuire, Cooper, Biegalski, Ivanov, Jellison, Boatner, Sales, Christen. Dielectric-constant-enhanced hall mobility in complex oxides, *Adv. Mater.* **2012**, *24*, 3965 – 3969.

Exploiting electronic—lattice instabilities through chemical tuning presents a novel pathway to enhanced transport in functional materials.

Alloying s^od^o transition metal ions (SOJT) or s²d¹⁰ main-group ions (lone pair stereochemistry) should enable property tunability over a wide temperature range.

Recently, systems with lone pair-bearing ions have been observed to exhibit unusual temperature dependence of structure and dynamics: These are ideal experimental platforms to further explore the relationship between proximal instability and functional properties.